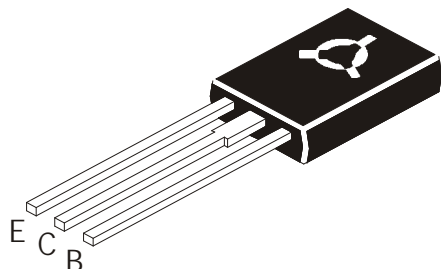


## SILICON EPITAXIAL POWER TRANSISTORS



**BD131**      **NPN**  
**BD132**      **PNP**

**TO-126**  
**Plastic Package**

### General Purpose Medium Power Applications

#### ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	BD131	BD132	UNIT
Collector -Base Voltage	$V_{CBO}$	70	45	V
Collector -Emitter Voltage	$V_{CEO}$	45	45	V
Emitter-Base Voltage	$V_{EBO}$	6	4	V
Collector Current Continuous	$I_C$	3		A
Peak	$I_{CM}$	6		A
Base Current Peak	$I_{BM}$	0.5		A
Reverse Base Current Peak	$-I_{BM}$	0.5		A
Total Device Dissipation upto $T_{amb}=60^\circ\text{C}$	$P_{tot}$	15		W
Junction Temperature	$T_j$	150		$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-65 to +150		$^\circ\text{C}$

#### Thermal Resistance

From Junction to Mounting Base	$R_{th(j-mb)}$	6	K/W
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#### ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$ unless specified otherwise)

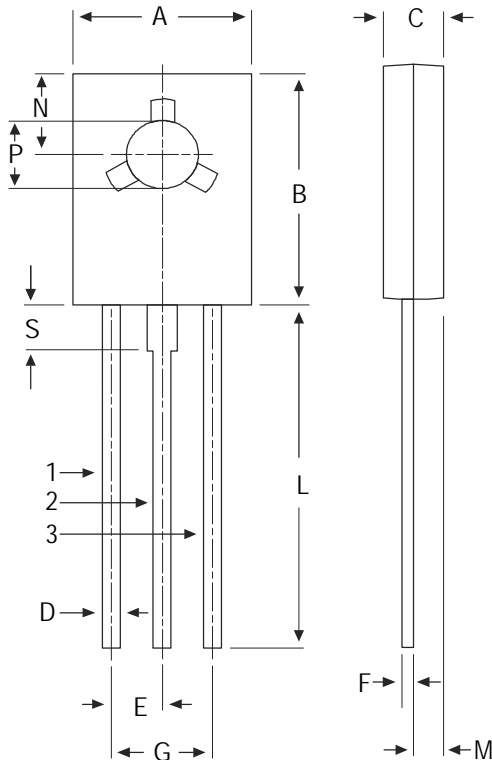
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=50\text{V}, I_E=0$ <b>BD131</b>		50	nA
		$V_{CB}=40\text{V}, I_E=0$ <b>BD132</b>		50	nA
		$V_{CB}=50\text{V}, I_E=0, T_j = 150^\circ\text{C}$ <b>BD131</b>		10	$\mu\text{A}$
		$V_{CB}=40\text{V}, I_E=0, T_j = 150^\circ\text{C}$ <b>BD132</b>		10	$\mu\text{A}$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=5\text{V}, I_C=0$ <b>BD131</b>		50	nA
		$V_{EB}=3\text{V}, I_C=0$ <b>BD132</b>		50	nA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 0.5\text{A}, I_B = 50\text{mA}$		0.3	V
		$I_C = 2\text{A}, I_B = 200\text{mA}$		0.7	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 0.5\text{A}, I_B = 50\text{mA}$		1.2	V
		$I_C = 2\text{A}, I_B = 200\text{mA}$		1.5	V
DC Current Gain	$h_{FE}$	$V_{CE} = 12\text{V}, I_C = 0.5\text{A}$	40		
		$V_{CE} = 1\text{V}, I_C = 2\text{A}$	20		

#### Dynamic Characteristics

Collector Capacitance	$C_C$	$I_E = 0, V_{CB} = 5\text{V}, f = 1\text{MHz}$ <b>BD131</b>		60	pF
Transition Frequency	$f_T$	$I_C = 0.25\text{A}, V_{CE} = 5\text{V}, f = 35\text{MHz}, T_{amb} = 25^\circ\text{C}$	60		MHz
DC Current Gain Ratio of the Complementary Pairs	$h_{FE1}/h_{FE2}$	$V_{CE} = 12\text{V}, I_C = 0.5\text{A}$		1.2	

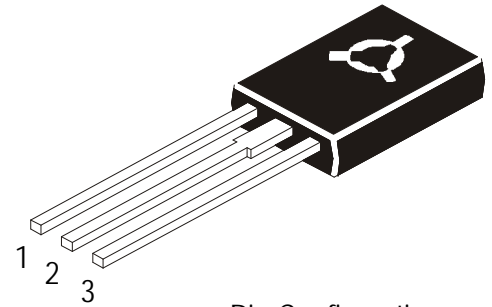
## TO-126 Plastic Package

### TO-126 (SOT-32) Plastic Package



DIM	MIN	MAX
A	7.4	7.8
B	10.5	10.8
C	2.4	2.7
D	0.7	0.9
E	2.25 TYP.	
F	0.49	0.75
G	4.5 TYP.	
L	15.7 TYP.	
M	1.27 TYP.	
N	3.75 TYP.	
P	3.0	3.2
S	2.5 TYP.	

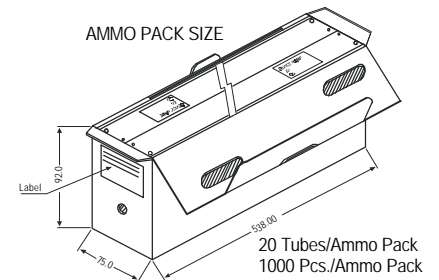
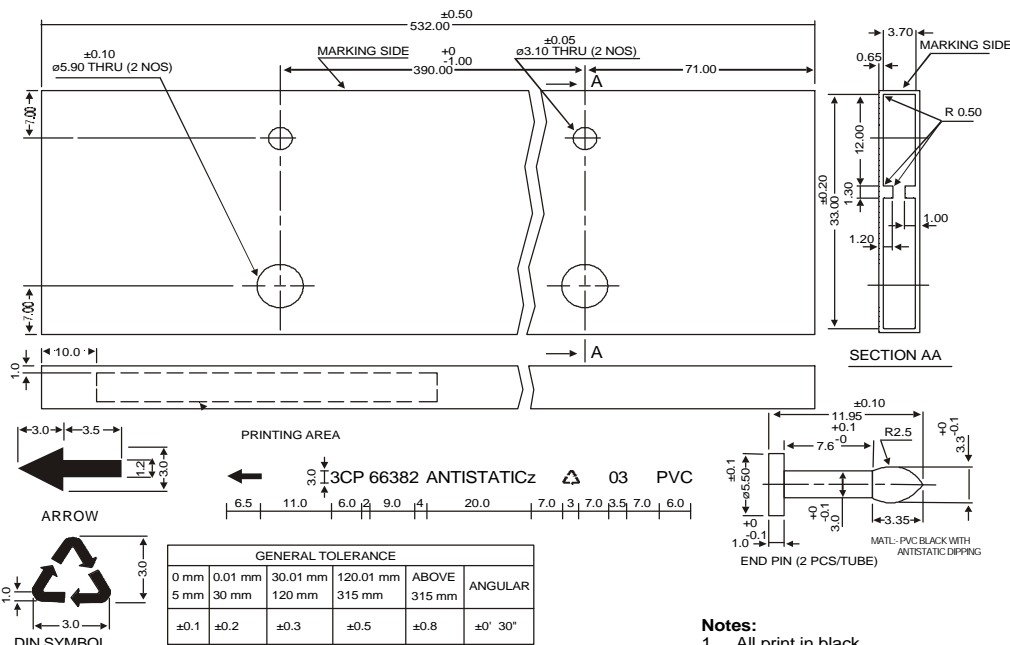
All dimensions in mm.



#### Pin Configuration

1. Emitter
2. Collector
3. Base

### TO-126 TUBE PACKING



### Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-126 Bulk	500 pcs/polybag	340 gm/500 pcs	3" x 7.5" x 7.5"	2K	17" x 15" x 13.5"	32K	31 kgs
TO-126 Tube	50 pcs/tube	73 gm/50 pcs	3" x 3.7" x 21.5"	1K	19" x 19" x 19"	10K	15 kgs

BD131\_132Rev\_1 120403D

### **Disclaimer**

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CDIL is a registered Trademark of  
Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.  
Telephone + 91-11-2579 6150 Fax + 91-11-2579 9569, 2579 5290  
e-mail sales@cdil.com www.cdil.com, www.cdilsemi.com